







## **IFN105** N-Channel JFET

#### **Features**

- InterFET N0016SH Geometry
- Low Noise: 5 nV/VHz Typical
- Japanese 2SK105 Replacement
- RoHS Compliant
- SMT, TH, and Bare Die Package options.

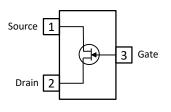
#### **Applications**

- · Audio Amplifiers
- · Small Signal Amplifier
- · Ultrahigh Impedance Pre-Amplifier

#### Description

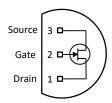
The -50V InterFET IFN105 is a replacement for the Japanese 2SK105. Targeted for sensitive amplifier stages with gate leakages typically less than 10pA at room temperatures.

#### **SOT23 Top View**





**TO-92 Bottom View** 





#### **Product Summary**

	Parameters	IFN105 Min	Unit	
BV <sub>GSS</sub>	Gate to Source Breakdown Voltage	-50	V	
I <sub>DSS</sub>	Drain to Source Saturation Current	0.5	mA	
V <sub>GS(off)</sub>	Gate to Source Cutoff Voltage	-0.25	V	
GFS	Forward Transconductance	2.1 Tvp	mS	

## Ordering Information Custom Part and Binning Options Available

Part Number	Description	Case	Packaging
IFN105	Through-Hole	TO-92	Bulk
SMP105	Surface Mount	SOT23	Bulk
	7" Tape and Reel: Max 3,000 Pieces		Minimum 1,000 Pieces
SMP105TR	13" Tape and Reel: Max 9,000 Pieces	SOT23	Tape and Reel
IFN105COT	Chip Orientated Tray (COT Waffle Pack)	СОТ	400/Waffle Pack
IFN105CFT	Chip Face-up Tray (CFT Waffle Pack)	CFT	400/Waffle Pack



**Disclaimer:** It is the Buyers responsibility for designing, validating and testing the end application under all field use cases and extreme use conditions. Guaranteeing the application meets required standards, regulatory compliance, and all safety and security requirements is the responsibility of the Buyer. These resources are subject to change without notice.









## **Electrical Characteristics**

Maximum Ratings (@ T<sub>A</sub> = 25°C, Unless otherwise specified)

	Parameters	Value	Unit
$V_{\text{RGS}}$	Reverse Gate Source and Gate Drain Voltage	-50	V
I <sub>FG</sub>	Continuous Forward Gate Current	50	mA
PD	Continuous Device Power Dissipation	300	mW
Р	Power Derating	2	mW/°C
TJ	Operating Junction Temperature	-55 to 125	°C
T <sub>STG</sub>	Storage Temperature	-65 to 175	°C

Static Characteristics (@ TA = 25°C, Unless otherwise specified)

			IFN105		
	Parameters	Conditions	Min	Max	Unit
V <sub>(BR)GSS</sub>	Gate to Source Breakdown Voltage	$V_{DS} = 0V$ , $I_{G} = -1\mu A$	-50		V
I <sub>GSS</sub>	Gate to Source Reverse Current	V <sub>GS</sub> = -30V, V <sub>DS</sub> = 0V		-1.0	nA
V <sub>GS(OFF)</sub>	Gate to Source Cutoff Voltage	V <sub>DS</sub> = 5V, I <sub>D</sub> = 1nA	-0.25	-4.5	V
I <sub>DSS</sub>	Drain to Source Saturation Current	$V_{GS} = 0V$ , $V_{DS} = 5V$ (Pulsed)	0.5	12	mA
I <sub>DF</sub>	Forward Diode Voltage	V <sub>DS</sub> = 0V, I <sub>GS</sub> = 10μA	0.4	0.8	V

**Dynamic Characteristics** (@ TA = 25°C, Unless otherwise specified)

			IFN105	
	Parameters	Conditions	Typical	Unit
G <sub>FS</sub>	Forward Transconductance	$V_{DS} = 5V, V_{GS} = 0V, f = 1kHz$	2.1	mS
Ciss	Input Capacitance	V <sub>DS</sub> = 10V, V <sub>GS</sub> = 0V, f = 1MHz	4.0	pF
Crss	Reverse Transfer Capacitance	V <sub>DS</sub> = 10V, V <sub>GS</sub> = 0V, f = 1MHz	1.0	pF



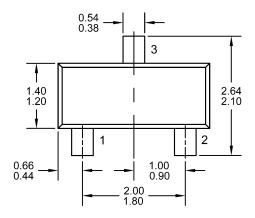


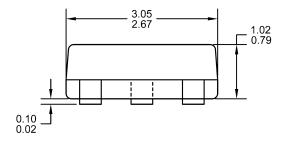


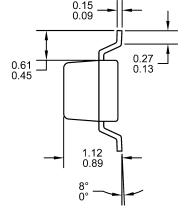


# SOT23 (TO-236AB) Mechanical and Layout Data

## **Package Outline Data**

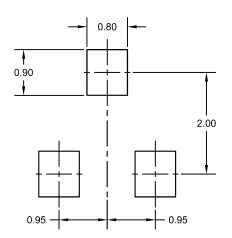






- 1. All linear dimensions are in millimeters.
- 2. Package weight approximately 0.12 grams
- 3. Molded plastic case UL 94V-0 rated
- For Tape and Reel specifications refer to InterFET CTC-021 Tape and Reel Specification, Document number: IF39002
- Bulk product is shipped in standard ESD shipping material
- 6. Refer to JEDEC standards for additional information.

#### **Suggested Pad Layout**



- 1. All linear dimensions are in millimeters.
- 2. The suggested land pattern dimensions have been provided for reference only. A more robust pattern may be desired for wave soldering.



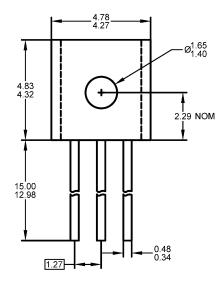


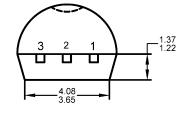


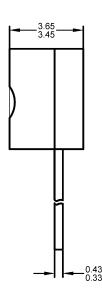


# **TO-92 Mechanical and Layout Data**

# **Package Outline Data**

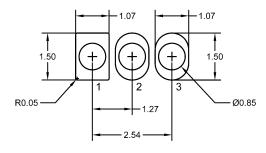






- 1. All linear dimensions are in millimeters.
- 2. Package weight approximately 0.19 grams
- 3. Molded plastic case UL 94V-0 rated
- Bulk product is shipped in standard ESD shipping material
- 5. Refer to JEDEC standards for additional information.

## **Suggested Through-Hole Layout**



- 1. All linear dimensions are in millimeters.
- The suggested land pattern dimensions have been provided as a straight lead reference only. A more robust pattern may be desired for wave soldering and/or bent lead configurations.